HE UNITED STATES PATENT AND TRADEMARK OFFICE

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In re A

Alan R. Reinberg et al.

Prior Application Serial No.: 09/740,256

Prior Application Filed:

December 19, 2000

Serial No.: 10/872,765

Filed: June 21, 2004

For: SMALL ELECTRODE FOR A

> CHALCOGENIDE SWITCHING DEVICE AND METHOD FOR

**FABRICATING SAME** 

Group Art Unit:

Unassigned

Examiner:

Unassigned

Atty Docket: MCRO:106--3/FLE

95-0412.03

Mail Stop Amendment Commissioner for Patents P.O. Box 1450 Alexandria, Virginia 22313-1450 **CERTIFICATE OF MAILING** 37 C.F.R. 1.8

I hereby certify that this correspondence is being deposited with the U.S. Postal Service with sufficient postage as First Class Mail in an envelope addressed to: Mail Stop Amendment, Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450, on the date below:

December 7, 2004

Date

Michael G. Fletcher

Sir:

## INFORMATION DISCLOSURE STATEMENT PURSUANT TO 37 C.F.R. §§ 1.97(b)(1) AND 1.98

In compliance with the duty of disclosure under 37 C.F.R. § 1.56(a), Applicants respectfully request that this Information Disclosure Statement be entered and that the listed references be considered by the Examiner and made of record. Under 37 C.F.R. § 1.98(e), copies of the listed domestic references are not required to be submitted to the Examiner. Therefore, only copies of the listed foreign references and other art are provided herewith.

In accordance with 37 C.F.R. § 1.97, this Information Disclosure Statement is not to be

construed as a representation that a search has been made, as an admission that the information cited

herein is, or is considered to be, material to patentability as defined in 37 C.F.R. §1.56(b), or as a

representation that no other possibly material information, as defined in 37 C.F.R. § 1.56(b), exists.

Furthermore, the references listed on the attached Form 1449 are not to be construed as an

admission that these references qualify as prior art as to the above-referenced application or any related

application. Rather, these references are being presented for the Examiner's consideration without

prejudice to Applicants' right to demonstrate that any of these references do not qualify as prior art should

the Examiner choose to apply any of these references.

The following information is listed below in accordance with 37 C.F.R. §1.98. Any

explanation of non-English language documents contained in this Information Disclosure Statement is

believed to constitute a concise explanation of the relevance of the listed reference as it is presently

understood by the individual designated in § 1.56(c) most knowledgeable about the content of the listed

reference, in accordance with 37 C.F.R. § 1.98(a)(3):

Respectfully submitted,

Date: December 7, 2004

Michael G. Fletcher

Reg. No. 32,777

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## Form PTO-1449 (modified)

List of Patents and Publications For Applicant's Information

Disclosure Statement

(Use several sheets if necessary)

ATTY. DOCKET NO. MCRO:106--3/FLE

SERIAL NO. 10/872,765

APPLICANT

Alan R. Reinberg et al.

FILING DATE June 21, 2004 GROUP Unassigned

## **U.S. PATENT DOCUMENTS**

EXAM. INIT.	REF. DES.	DOCUMENT NUMBER	DATE	NAME	CLASS	SUB CLASS	FILING DATE
<del></del>		3,423,646	01/21/69	Cubert et al.	317	234	
		3,602,635	08/31/71	Romankiw	174	68.5	
		3,796,926	03/12/74	Cole et al.	317	234 R	
		3,877,049	04/08/75	Buckley	357	2	
		3,886,577	05/75	Buckley	257	3	
•		4,099,260	07/04/78	Lynes et al.	365	105	
		4,115,872	09/19/78	Bluhm	365	163	
		4,174,521	11/13/79	Neale	357	45	
		4,194,283	03/25/80	Hoffmann	29	571	
		4,227,297	10/14/80	Angerstein	29	571	
		4,203,123	05/13/80	Shanks	357	2	
		4,272,562	06/09/81	Wood	427	87	
·		4,433,342	02/21/84	Patel et al.	357	2	
	-	4,458,260	07/03/84	McIntyre et al.	357	30	
		4,499,557	02/12/85	Holmberg et al.	365	163	
		4,502,208	03/05/85	McPherson	29	584	
		4,502,914	03/05/85	Trumpp et al.	156	643	
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		4,677,742	07/07/87	Johnson	29	591	
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		4,795,657	01/03/89	Formigoni et al.	427	96	
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EXAM. INIT.	REF. DES.	DOCUMENT NUMBER	DATE	NAME	CLASS	SUB CLASS	FILING DATE
		4,823,181	04/18/89	Mohsen et al.	357	51	
<u></u>		4,876,220	10/24/89	Mohsen et al.	437	170	
		4,876,668	10/24/89	Thakoor et al.	365	163	
		4,881,114	11/14/89	Mohsen et al.	357	54	
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		5,144,404	09/01/92	Iranmanesh et al.	357	51	
		5,166,096	11/24/92	Cote et al.	437	195	
		5,166,758	11/24/92	Ovshinsky et al.	257	3	
		5,177,567	01/05/93	Klersy et al.	257	4	
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		5,296,716	03/22/94	Ovshinsky et al.	257	3	·
		5,335,219	08/02/94	Ovshinsky et al.	369	288	
		5,341,328	08/23/94	Ovshinsky et al.	365	163	
		5,359,205	10/25/94	Ovshinsky	257	3	
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		5,714,768	02/03/98	Ovshinsky et al.	257	40	10/24/95
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		FO	REIGN PA	ATENT DOCU	MENTS				
EXAM. INIT.	REF. DES.	DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUB CLASS	TRANSLATION YES/NO		
-		1 319 388	06/06/73	Great Britain	H01L	9/00	Yes		
		0 117 045 A3	08/29/84	Europe	H01L	45/00	Yes		
		JP 60109266	06/14/85	Japan	H01L	27/10	Yes - Abstract		
ОТІ	HER A	RT (Author,	Title, Jou	ırnal, Volume	, Pertine	nt Page	es, & Date)		
			_	n-Current Pulses on Po h Boron and Phospho	= =				
		Neale and Aseltine, "The Application of Amorphous Materials to Computer Memories," <i>IEEE</i> , 20(2):195-205, 1973.							
		Pein and Plummer, "Performance of the 3-D Sidewall Flash EPROM Cell," <i>IEEE</i> , 11-14, 1993.  Post and Ashburn, "Investigation of Boron Diffusion in Polysilicon and its Application to the Design of p-n-p Polysilicon Emitter Bipolar Transistors with Shallow Emitter Junctions," <i>IEEE</i> , 38(11):2442-2451, 1991.							
		Post et al., "Polysilicon Emitters for Bipolar Transistors: A Review and Re-Evaluation of and Experiment," <i>IEEE</i> , 39(7):1717-1731, 1992.  Post and Ashburn, "The Use of an Interface Anneal to Control the Base Current and Emitt Resistance of p-n-p Polysilicon Emitter Bipolar Transistors," <i>IEEE</i> , 13(8):408-410, 1992.							
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	Rose et al., "Amorphous Silicon Analogue Memory Devices," J. Non-Crystalline S. 115:168-170, 1989.						lline Solids,		
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		Oakley et al., "Pillars - The Way to Two Micron Pitch Multilevel Metallisation," IEEE, 23-29, 1984.							
		Prince, "Semiconductor Memories," A Handbook of Design, Manufacture, and Application, 2 <sup>nd</sup> Ed., pgs. 118-123.							
EXAMIN	ER			DATE CONSIDERED					

EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

Information Disclosure Statement--PTO-1449 (Modified)